



74AHCT594

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8-BIT SHIFT REGISTER WITH 8-BIT OUTPUT REGISTER

Description

The 74AHCT594 is an advanced high speed CMOS device that is designed to be pin compatable with 74LS low power Schottky types.

An eight bit shift register accepts data from the serial input (DS) on each positive transition of the shift register clock (SHCP). When asserted low the shift register reset function (SHR) sets all shift register values to zero and is independent of all clocks. Also when asserted low, the storage register reset function (STR) sets all shift register values to zero and is independent of all clocks.

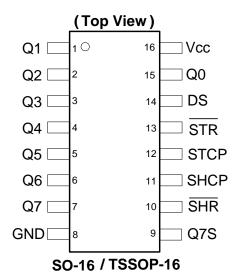
Data from the input serial shift register is placed in the output register with a rising pulse on the storages resister clock (STCP). The storage resister includes output Q7S which is used for cascading information between devices. As the information moves into the storage register, it is asserted on the push-pull outputs Q0-Q7.

All registers capture data on rising edge and change output on the falling edge. If both clocks are connected together, the input shift register is always one clock cycle ahead of the output register.

Features

- Wide Supply Voltage Range from 4.5V to 5.5V
- Sinks or sources 8mA at V_{CC} = 4.5V
- · CMOS low power consumption
- Schmitt Trigger Action at All Inputs
- Inputs accept up to 6.0V
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115-A)
 - Exceeds 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

- General Purpose Logic
- Serial to Parallel Data conversion
- Capture and hold data for extended periods of time.
- Allow simple serial bit streams from a microcontroller to control as many peripheral lines as needed.
- Wide array of products such as:
 - Computer Peripherals
 - Appliances
 - Industrial control

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

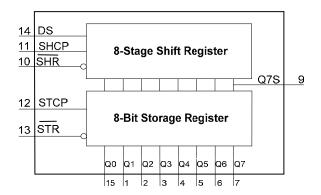
Click here for ordering information, located at the end of datasheet



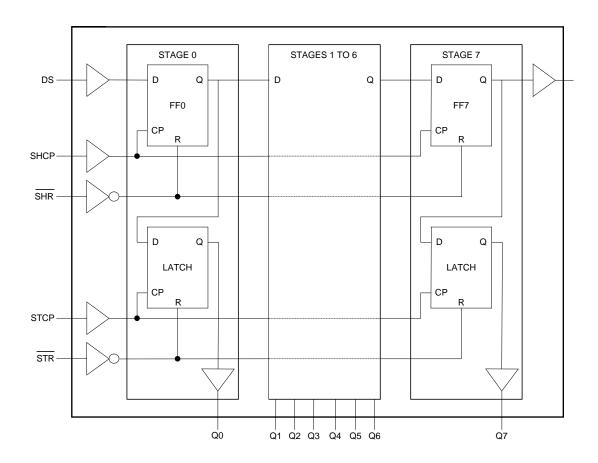
Pin Descriptions

Pin Number	Pin Name	Description
1	Q1	Parallel Data Output 1
2	Q2	Parallel Data Output 2
3	Q3	Parallel Data Output 3
4	Q4	Parallel Data Output 4
5	Q5	Parallel Data Output 5
6	Q6	Parallel Data Output 6
7	Q7	Parallel Data Output 7
8	GND	Ground
9	Q7S	Serial Data Output
10	SHR	Shift Register Reset active low
11	SHCP	Shift Register Clock Input
12	STCP	Storage Register Clock Input
13	STR	Storage Register Reset active low
14	DS	Serial Data input
15	Q0	Parallel Data Output 0
16	Vcc	Supply Voltage

Functional Diagram



Logic Diagram



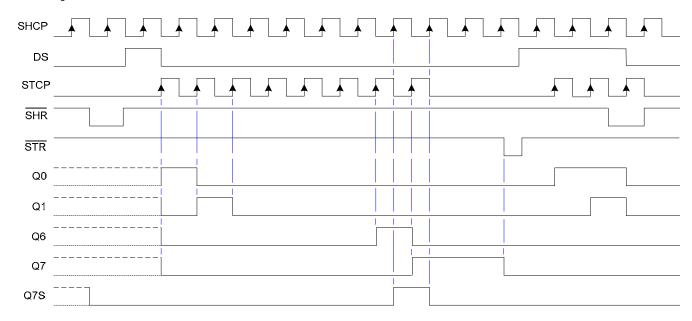


Functional Description and Timing Diagram

	Control		ntrol		Output		Fd'
SHR	STR	SHCP	STCP	DS	Q7S	Qn	Function
L	Х	Х	Χ	Х	L	NC	Clear Shift Register
Х	L	Х	Х	Χ	NC	L	Clear Storage Register
Н	Х	↑	L	H or L	Q6S	NC	Loads DS into shift register stage 0. All Q _S shifted
Н	Н	Х	1	Х	NC	Qs	Contents of shift register moved to starge register all Q _S -> Q _N
Н	Н	1	1	H or L	Q6S	QnS	Shift Register one pulse count ahead of storage register.

H=HIGH voltage state L=LOW voltage state ↑=LOW to HIGH transition X= don't care - high or low (not floating)

NC= No change



Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
Vo	Voltage applied to output in high or low state	-0.3 to V _{CC} +0.5	V
lıĸ	Input Clamp Current V _I < -0.5V	-20	mA
I _{OK}	Output Clamp Current Vo<-0.5V	-20	mA
I _{OK}	Output Clamp Current V _O > V _{CC} +0.5V	20	mA
Io	Continuous output current	±25	mA
Icc	Continuous current through Vcc	75	mA
I _{GND}	Continuous current through GND	-75	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
Ртот	Total Power Dissipation	500	mW

Notes: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	Supply Voltage	_	4.5	5.5	V
V_{I}	Input Voltage	_	0	5.5	V
Vo	Output Voltage	Active Mode	0	Vcc	V
Δt/ΔV	Input transition Rise or Fall Rate	V _{CC} = 4.5V to 5.5V	-	20	ns/V
T_A	Operating Free-Air Temperature	_	-40	+125	°C

Note:

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Cumbal	Davamatar	Test Conditions	V	T	₄ = +25°	,C	T _A = -40°C	C to +85°C	T _A = -40°C	to +125°C	Unit
Symbol	Symbol Parameter	rest Conditions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Unit
V _{IH}	High-level Input Voltage	-	4.5V to 5.5V	2.0	-	-	2.0	-	2.0	-	V
V_{IL}	Low-level input voltage	_	4.5V to 5.5V	-	-	0.8	-	0.8	=	0.8	٧
1/	High Level	I _{OH} = -50μA	4.5V	4.4	4.5	-	4.4	-	4.4	-	V
Voh	Output Voltage	I _{OH} = -8mA	4.5V	3.94	=	-	3.80	-	3.70	-	V
\/	Low-level	I _{OL} = 50μA	4.5V	-	0	0.1	-	0.1).1 –	0.1	V
V_{OL}	Output Voltage	I _{OL} = 8mA	4.5V	_	-	0.36	-	0.44	-	0.55	V
lį	Input Current	V _I = GND or 5.5V	0V to 5.5V	_	0.1	±0.1	-	± 1	-	± 2	μΑ
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}$ $I_O = 0$	5.5V	_	-	4.0	-	40	_	80	μΑ
ΔΙςς	Additional Supply Current per Input	V _I = V _{CC} -2.1V I _O = 0	4.5V to 5.5V	-	-	1.35	-	1.5	-	1.5	mA
Ci	Input Capacitance	V _i = V _{CC} or GND	5.5V	-	3.5	10	-	10	-	10	pF

^{5.} Unused inputs should be held at V_{CC} or Ground.



Switching Characteristics

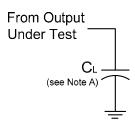
Symbol /	D'	Table Open did and	.,	Т	_A = +25°	С	-40°C t	o +85°C	-40°C to	+125°C	1114
Parameter	Pins	Test Conditions	V _{CC}	Min	Тур	Max	Min	Max	Min	Max	Unit
f _{MAX} Maximum Frequency	SHCP or STCP	Figure 2 C _L = 15pF	4.5V to 5.0V	90	160	-	80	I	70	-	MHz
	SHCP HIGH or LOW	Figure 2 C _L = 50pF	4.5V to 5.0V	5.5	-	-	6.0	-	6.5	-	
t _W Pulse Width	STCP HIGH or LOW	Figure 2 C _L = 50pF	4.5V to 5.0V	5.5	=	_	6.0	I	6.5	=	ns
	SHR and STR HIGH or LOW	Figure 2 C _L = 50pF	4.5V to 5.0V	5.2		=	5.5	I	6.0	-	
	DS to SHCP	Figure 2 C _L = 50pF	4.5V to 5.0V	3.0	-	-	3.0	=	3.5	-	
t _{SU}	SHR to STCP	Figure 2 C _L = 50pF	4.5V to 5.0V	5.0	_	_	5.0	-	5.5	-	ns
Set-up Time	SHCP to STCP	Figure 2 C _L = 50pF	4.5V to 5.0V	5.0	-	-	5.0	ı	5.5	=	
t _H Hold Time	DS to SHCP	Figure 2 C _L = 50pF	4.5V to 5.0V	5	2.0		=	2.0	=	2.5	ns
t _{REC} Recovery Time	SHR to SHCP and STR to STCP	Figure 2 C _L = 50pF	4.5V to 5.0V	10	2.9	-	_	3.3	_	3.8	ns
	SHCP toQ7S	Figure 2 C _L = 15pF	4.5V to 5.0V	-	4.1	6.7	1.8	7.6	1.8	8.3	
t _{PLH}	3HCF 10Q/3	Figure 2 C _L = 50pF	4.5V to 5.0V	_	5.4	8.8	2.4	10.1	2.4	11.0	ns
Propagation Delay	STCP to Qn	Figure 2 C _L = 15pF	4.5V to 5.0V	-	3.7	6.1	1.9	6.9	1.9	7.2	115
	STOP to QII	Figure 2 C _L = 50pF	4.5V to 5.0V	=	5.2	8.5	2.6	9.7	2.6	10.5	
	SHCP to Q7S	Figure 2 C _L = 15pF	4.5V to 5.0V	_	4.1	6.7	1.8	7.6	1.8	8.3	
	311CF to Q/3	Figure 2 C _L = 50pF	4.5V to 5.0V	-	5.4	8.8	2.4	10.1	2.4	11.0	ns
	STCP to Qn	Figure 2 C _L = 15pF	4.5V to 5.0V	-	3.7	6.1	1.9	6.9	1.9	7.2	113
t _{PHI}	STOP to QII	Figure 2 C _L = 50pF	4.5V to 5.0V	_	5.2	8.5	2.6	9.7	2.6	10.5	
Propagation Delay	SHR to Q7S	Figure 2 C _L = 15pF	4.5V to 5.0V	-	4.3	7.0	2.4	8.0	2.4	8.7	ns
	טוארוט עויס	Figure 2 C _L = 50pF	4.5V to 5.0V	-	5.4	8.8	2.7	10.1	2.7	11.0	113
	STR to Qn	Figure 2 C _L = 15pF	4.5V to 5.0V	-	4.5	7.4	2.3	8.4	2.3	9.2	ns
	3 I K IO QII	Figure 2 C _L = 50pF	4.5V to 5.0V	-	5.7	9.4	3.1	10.7	3.1	11.7	113

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

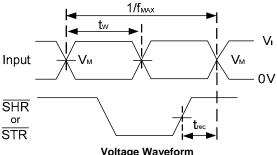
Parameter		Test Conditions	V _{CC} = 5V Typ	Unit
C_{pd}	Power dissipation capacitance	$f = 1$ MHz all outputs switching-no load $V_I = GND TO V_{CC}$ -1.5V	51	pF



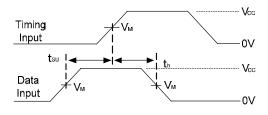
Parameter Measurement Information



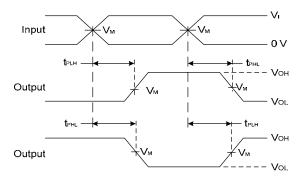
W	Inj	outs	, , , , , , , , , , , , , , , , , , ,	
V _{CC}	Vı	t _r /t _f	V _M	
4.5V	V _{CC}	6ns	V _{CC} /2	
5.0V	V _{CC}	6ns	V _{CC} /2	



Voltage Waveform Pulse Duration and Recovery Time



Voltage Waveform Set-up and Hold Times



Voltage Waveform **Propagation Delay Times Inverting and Non Inverting Outputs**

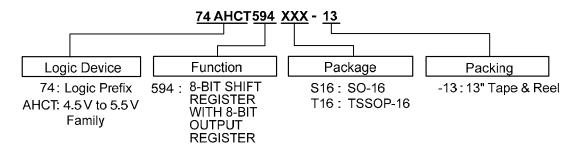
Notes:

- A. Includes test lead and test apparatus capacitance.
- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz.
- C. Inputs are measured separately one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{PD} .

Figure 2 Load Circuit and Voltage Waveforms



Ordering Information

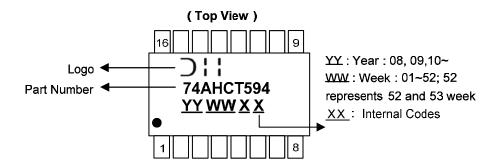


Device	Backage Code	Dookoging	7" Tape and Reel (Note 6)			
Device	Package Code	Packaging	Quantity	Part Number Suffix		
74AHCT594S16-13	S16	SO-16	2500/Tape & Reel	-13		
74AHCT594T16-13	T16	TSSOP-16	2500/Tape & Reel	-13		

Note: 6. The taping orientation is located on our website at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) SO-16, TSSOP16



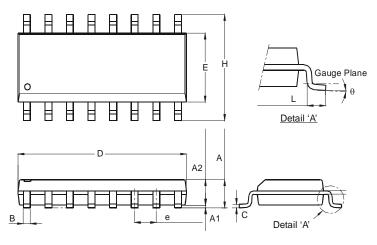
Part Number	Package
74AHCT594S16	SO-16
74AHCT594T16	TSSOP-16



Package Outline Dimensions (All dimensions in mm.)

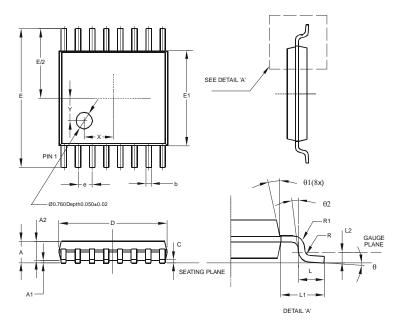
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-16



SO-16						
Dim	Min	Max				
Α	1.40	1.75				
A1	0.10	0.25				
A2	1.30	1.50				
В	0.33	0.51				
С	0.19	0.25				
D	9.80	10.00				
Е	3.80	4.00				
е	1.27	Тур				
Η	5.80	6.20				
١	0.38	1.27				
Θ	0°	8°				
All D	imension	s in mm				

Package Type: TSSOP-16



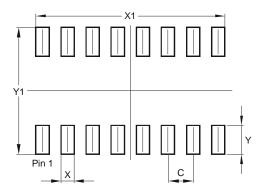
TSSOP-16						
Dim	Min	Max	Тур			
Α	-	1.08	-			
A 1	0.05	0.15	-			
A2	0.80	0.93	-			
q	0.19	0.30	-			
O	0.09	0.20	-			
D	4.90	5.10	-			
Е	6	.40 BS	SC			
E1	4.30	4.50	-			
е		.65 BS	SC			
L	0.45	0.75	-			
L1	1	.00 R	EF			
L2	C	.25 BS	SC			
R	0.09	-	-			
R1	0.09	1	-			
Χ	-	-	1.350			
Υ	-	1	1.050			
Θ	0°	8°	-			
Θ1	5°	15°	-			
Θ2	0°	-	-			
All Dimensions in mm						



Suggested Pad Layout

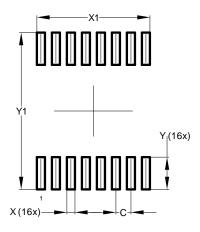
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-16



Dimensions	Value (in mm)
С	1.270
Х	0.670
X1	9.560
Y	1.450
Y1	6.400

Package Type: TSSOP-16



Dimensions	Value (in mm)
С	0.650
Х	0.350
X1	4.900
Y	1.400
Y1	6.800



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